

MP6211/MP6212

3.3V/5V, Single-Channel 1A

Current-Limited Power Distribution Switches

The Future of Analog IC Technology

DESCRIPTION

MP6211/MP6212 The single-channel Power Distribution Switch features internal current limiting to prevent damage to host devices due to faulty load conditions. The MP6211/MP6212 Analog switch has $90m\Omega$ on-resistance and operates from 2.7V to 5.5V input. It is available with guaranteed current limits, making it ideal for load switching applications. The MP6211/MP6212 has built-in protection for both over current and increased thermal stress. For over current, the device will limit the current by changing to a constant current mode.

As the temperature increases as a result of short circuit, the device will shut off. The device will recover once the device temperature reduces to approx 120°C.

The MP6211/MP6212 is available in an 8-PIN SOIC package with exposed pad.

FEATURES

- 1A Continuous Current
- Accurate Current Limit
- 2.7V to 5.5V Supply Range
- 90uA Quiescent Current
- 90mΩ MOSFET
- Thermal-Shutdown Protection
- Under-Voltage Lockout
- 8ms FLAG Deglitch Time
- No FLAG Glitch During Power Up
- Reverse Current Blocking
- Active High & Active Low Options
- SOIC8E package
- UL Recognized: E322138

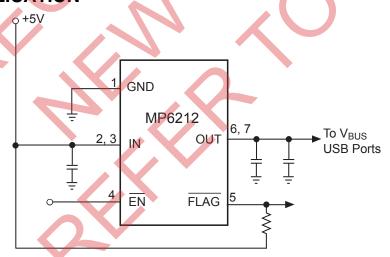
APPLICATIONS

- Smartphone and PDA
- Portable GPS Device
- Notebook PC
- Set-top-box
- Telecom and Network Systems
- **USB** Power Distribution

All MPS parts are lead-free, halogen free, and adhere to the RoHS directive. For MPS green status, please visit MPS website under Quality

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TYPICAL APPLICATION



SINGLE-CHANNEL



UL Recognized Component

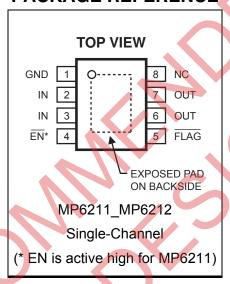


ORDERING INFORMATION

Part Number*	Enable	Switch	Maximum Continuous Load Current	Typical Short- Circuit Current @ T _A =25C	Package	Top Marking	Temperature
MP6211DN	Active High	Single	1.0A	1.5A	SOIC8E	6211D	-40°C to +85°C
MP6212DN	Active Low	Single	1.0A	1.5A	SOIC8E	6212D	40 0 10 100 0

* For Tape & Reel, add suffix –Z (eg. MP6211_MP6212DN–Z). For RoHS Compliant Packaging, add suffix –LF. (eg. MP6211_MP6212DN–LF–Z)

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)

IN0	31/ to +6 01/
EN, FLAG, OUT to GND0	.3V to +6.0V
Continuous Power Dissipation. (TA	= +25°C) ⁽²⁾
SOIC8E	2.5W
Junction Temperature	150°C
Lead Temperature	260°C
Storage Temperature65°	C to +150°C
Operating Temperature _40)°C to +85°C

Thermal Resi	stance ⁽³⁾	$oldsymbol{ heta}_{JA}$	$\boldsymbol{\theta}_{JC}$	
SOIC8E		50	10	°C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX)-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) Measured on JESD51-7 4-layer PCB.



ELECTRICAL CHARACTERISTICS (4)

 $V_{\text{IN}}=5V$, $T_{\text{A}}=+25^{\circ}\text{C}$, unless otherwise noted.

Parameter	Condition	Min	Тур	Max	Units
IN Voltage Range		2.7		5.5	V
Supply Current	Single Channel		90	120	μA
Shutdown Current	Device Disable, V _{OUT} =float, V _{IN} =5.5V		1		μA
Off Switch Leakage	Device Disable, V _{IN} =5.5V		1		μA
Current Limit		1.1	1.5	2.2	Α
Trip Current	Current Ramp (slew rate≤100A/s) on Output		1.7	2.4	Α
Under-voltage Lockout	Rising Edge	1.95		2.65	V
Under-voltage Hysteresis			250		mV
FET On Resistance	I _{OUT} =100mA (-40°C≤T _A ≤85°C)		90	130	mΩ
EN Input Logic High Voltage		2			V
EN Input Logic Low Voltage				0.8	V
FLAG Output Logic Low Voltage	I _{SINK} =5mA		10	0.4	V
FLAG Output High Leakage Current	V _{IN} =V _{FLAG} =5.5V			1	μА
Thermal Shutdown			140		°C
Thermal Shutdown Hysteresis			20		°C
V _{OUT} Rising Time, Tr ⁽⁵⁾	V_{IN} =5.5 V , CL=1 u F, RL=5.5 Ω V_{IN} =2.7 V , CL=1 u F, RL=5.5 Ω		0.9		ms ms
V	V_{IN} =5.5V, CL=1uF, RL=5.5 Ω			0.5	ms
V _{OUT} Falling Time, Tf ⁽⁶⁾	V _{IN} =2.7V, CL=1uF, RL=5.5Ω			0.5	ms
Turn On Time, Ton (7)	C _L =100μF, RL=5.5Ω			3	ms
Turn Off Time, Toff (8)	C _L =100μF, RL=5.5Ω			10	ms
FLAG Deglitch Time		4	8	15	ms
ENx Input Leakage			1		μA
Reverse Leakage Current	OUT=5.5V, IN=GND		0.2		μA

NOTES:

- Production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization. Measured from 10% to 90%.
- Measured from 90% to 10%
- 7) Measured from (50%) EN signal to (90%) output signal. 8) Measured from (50%) EN signal to (10%) output signal.

MP6211_MP6212 Rev. 1.3



PIN FUNCTIONS

SOIC8	Name	Description
1	GND Expose Pad	Ground. Connect exposed pad to GND plane for optimal thermal performance.
2, 3	IN	Input Voltage. Accepts 2.7V to 5.5V input.
4	EN	Enable Input, Active Low: (MP6212), Active High: (MP6211)
5	FLAG	IN-to-OUT Over-current, active-low output flag. Open-Drain.
6, 7	OUT	Power-Distribution Switch Output.
8	N/C	No Connect. Not internally connected.

TYPICAL PERFORMANCE CHARACTERISTICS

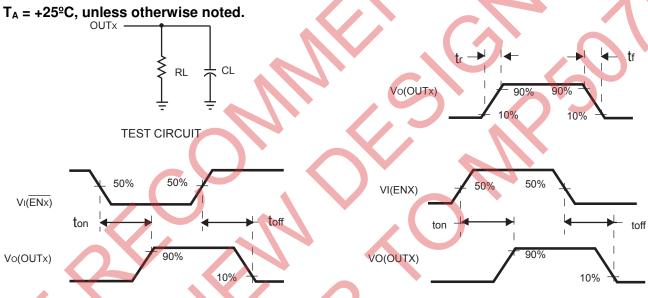


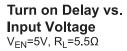
Figure 1—Test Circuit and Voltage Waveforms

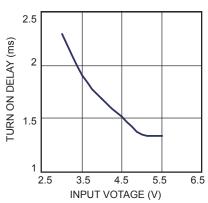
VOLTAGE WAVEFORMS



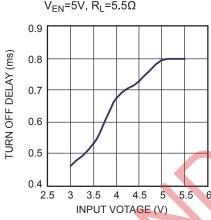
TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{IN}=5.5V$, $C_{L}=2.2uF$, $T_{A}=+25^{\circ}C$, unless otherwise noted.

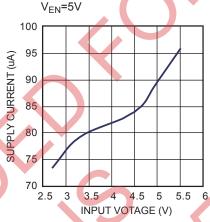




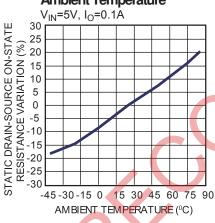
Turn off Delay vs. Input Voltage V_{EN} =5V, R_L =5.5 Ω



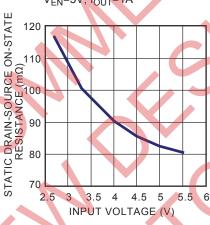
Supply Current, Output Enabled vs. Input Voltage



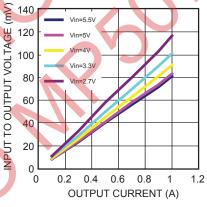
Static Drain-Source On-State Resistance Variation vs. **Ambient Temperature**



Static Drain-Source On-State Resistance vs. Input Voltage V_{EN}=5V, I_{OUT}=1A

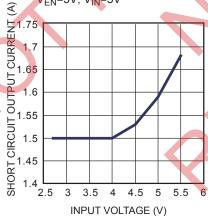


Input to Output Voltage vs. Load Current V_{EN}=5V

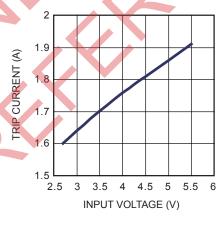


Short Circuit Output Current vs. Input Voltage

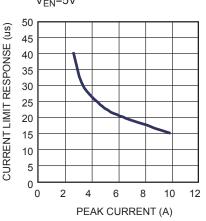




Threshold Trip Current vs. Input Voltage V_{EN}=5V



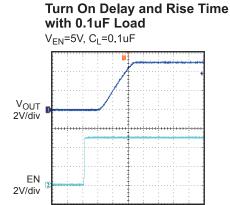
Current Limit Response Time vs. Peak Current V_{EN}=5V



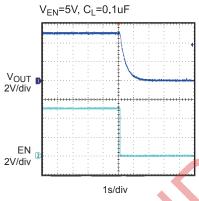


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

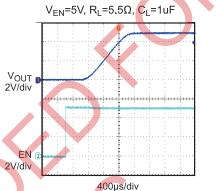
 $V_{IN}=5.5V$, $T_A=+25^{\circ}C$, unless otherwise noted.



Turn Off Delay and Fall Time with 0.1uF Load



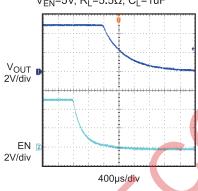
Turn on Delay and Rise Time with 1uF Load



Turn off Delay and Fall Time with 1uF Load

400µs/div

 V_{EN} =5V, R_L =5.5 Ω , C_L =1uF



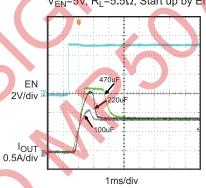
1Ω Load Connected to **Enabled Device**

V_{EN}=5V, C_L=1uF



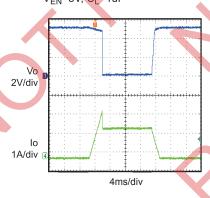
Inrush Current with Different Load Capacitance

 V_{EN} =5V, R_L=5.5 Ω , Start up by EN



Threshold Trip Current with Ramped Load on Enabled Device

V_{EN}=5V, C_L=1uF



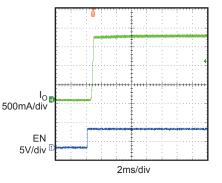
Ramped Load on **Enabled Device**

V_{EN}=5V, C_L=1uF



Short Circuit Current, Device Enabled into Short

V_{EN}=5V, C_L=1uF





FUNCTION BLOCK DIAGRAM

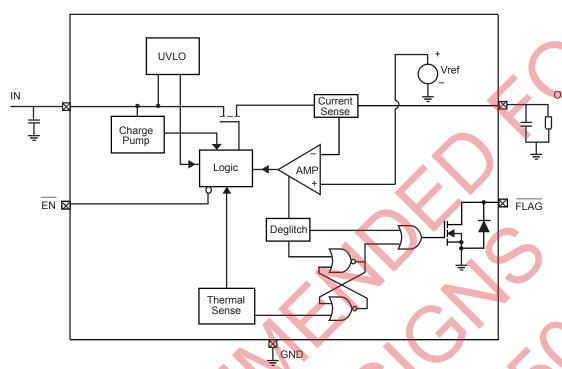


Figure 2—Functional Block Diagram



DETAILED DESCRIPTION

Over Current

When the load exceeds trip current (minimum threshold current triggering constant-current mode) or a short is present, MP6211/MP6212 switches into to a constant-current mode (current limit value). MP6211/MP6212 will be shutdown only if the overcurrent condition stays long enough to trigger thermal protection.

Trigger overcurrent protection for different overload conditions occurring in applications:

- 1) The output has been shorted or overloaded before the device is enabled or input applied. MP MP6211/MP6212 detects the short or overload and immediately switches into a constant-current mode.
- 2) A short or an overload occurs after the device is enabled. After the current-limit circuit has been tripped (reached the trip current threshold), the device switches into constantcurrent mode. However, high current may flow for a short period of time before the current-limit circuit can react.
- 3) Output current has been gradually increased beyond the recommended operating current. The load current rises until the trip current threshold is reached or until the thermal limit of the device is exceeded. The MP6211/ MP6212 is capable of delivering current up to the trip current threshold without damaging the device. Once the trip threshold has been reached, the device switches into constant-current mode.

Flag Response

The FLAG pin is an open drain configuration. This FAULT will report a fail mode after an 8ms deglitch timeout. This is used to ensure that no false fault signals are reported. This internal deglitch circuit eliminates the need for extend components. The FLAG pin is not deglitched during an over temp. or a voltage lockout.

Thermal Protection

The purpose of thermal protection is to prevent damage in the IC by allowing exceptive current to flow and heating the junction. The die temp. is internally monitored until the thermal limit is reached. Once this temp, is reached, the switch will turn off and allow the chip to cool. The switch has a built-in hysteresis.

Under-voltage Lockout (UVLO)

This circuit is used to monitor the input voltage to ensure that the MP6211/6212 is operating correctly. This UVLO circuit also ensures that there is no operation until the input voltage reaches the minimum spec.

Enable

The logic pin disables the chip to reduce the supply current. The device will operate once the enable signal reaches the appropriate level. The input is compatible with both COMS and TTL.

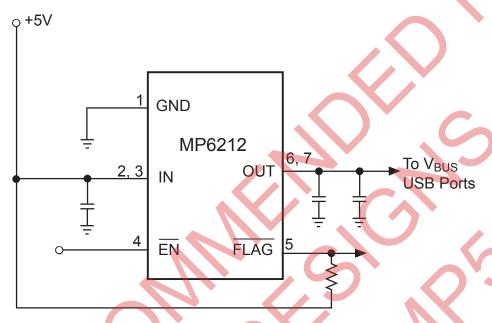


APPLICATION INFORMATION

Power-Supply Considerations

Over 10µF capacitor between IN and GND is recommended. This precaution reduces power-supply transients that may cause ringing on the input and improves the immunity of the device to short-circuit transients.

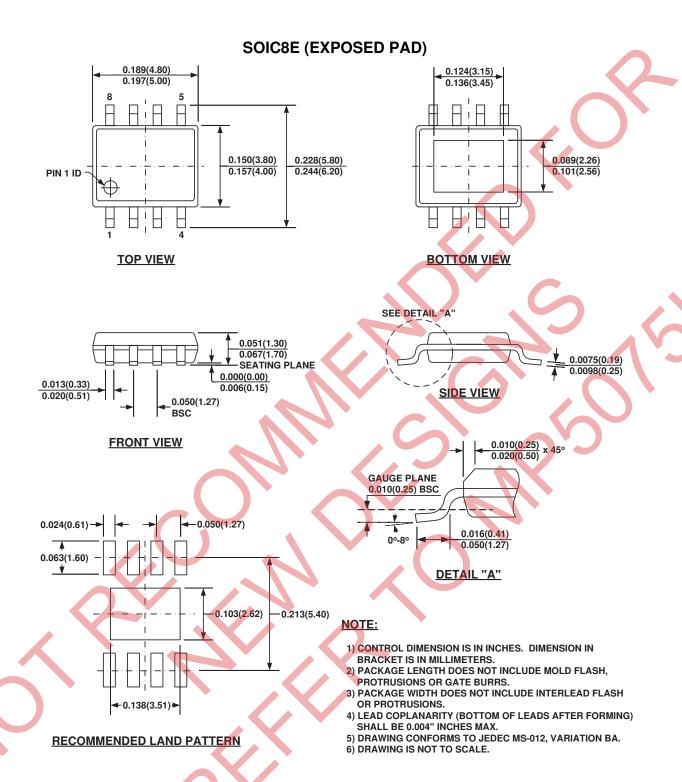
In order to achieve smaller output load transient ripple, placing a high-value electrolytic capacitor on the output pin(s) is recommended when the load is heavy.



SINGLE-CHANNEL

Figure 3—Application Circuit





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